

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	17	(differential adj variable adj capacitor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 14:27
S2	298	differential with (variable adj capacitor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/16 15:10
S3	4	S2 and (gate with polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/16 15:13
S4	30	S2 and VCO	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/16 15:14
S5	103475	capacitor and gate and well	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 14:26
S6	34850	si and gate and well	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 14:27
S7	18	(differential adj variable adj capacitor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 14:29
S8	3	S7 and gate and well	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 14:28
S9	1	S7 and gate and ((n or p) with well)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 14:34
S10	4	S7 and gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 14:32

S11	1984	capacitor and differential and variable and gate and ((n or p) with well)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 14:37
S12	52	(capacitor with differential with variable) and gate and ((n or p) with well)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 14:38
S13	1826	257/532.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 17:59
S14	43	(MOS with capacitor) and (n with well) and (n with region with three)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 17:13
S15	188	257/595.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 17:59